LINEAR SYSTEMS

Over Three Decades of Quality Through Innovation

SD-SST210/214

N-CHANNEL LATERAL DMOS SWITCH

PART NUMBER	$V_{(BR)DS}$ Min (V)	$V_{(GS)th}$ Max (V)	$r_{DS(on)}$ Max (Ω)	C_{rss} Max (pF)	t_{ON} Max (ns)
SD210DE	30	1.5	45 @ V_{GS}=10V	0.5	2
SD214DE	20	1.5	45 @ V_{GS}=10V	0.5	2
SST210	30	1.5	50 @ V_{GS}=10V	0.5	2
SST214	20	1.5	50 @ V_{GS}=10V	0.5	2

PRODUCT SUMMARY

Features

- Ultra-High Speed Switching—t_{ON}: 1ns
- Ultra-Low Reverse Capacitance: 0.2pF
- Low Guaranteed r_{DS} @5V
- Low Turn-On Threshold Voltage
- N-Channel Enhancement Mode

Benefits

- High-Speed System Performance
- Low Insertion Loss at High Frequencies
- Low Transfer Signal Loss
- Simple Driver Requirement
- Single Supply Operation

Applications

- Fast Analog Switch
- Fast Sample-and-Holds
- Pixel-Rate Switching
- DAC Deglitchers
- High-Speed Driver

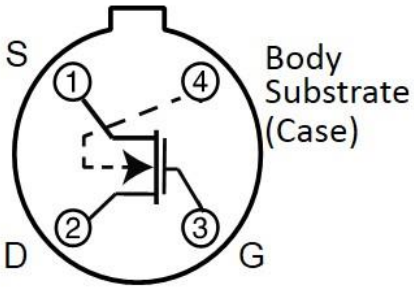
Description

The SD210DE/214 and SST210/214 are enhancement-mode MOSFETs designed for high speed low-glitch switching in audio, video and high-frequency applications. The SD214DE and SST214 are normally used for ±10-V analog switching. These MOSFETs utilize lateral construction to achieve low capacitance and ultra-fast switching speeds. These MOSFETs do not have a gate protection Zener diode which results in lower gate leakage and ± voltage capability from gate to substrate. A poly-silicon gate is featured for manufacturing reliability.

For similar products see: quad array—SD5000/5400 series, Zener protected—SD211DE/SST211 Series.

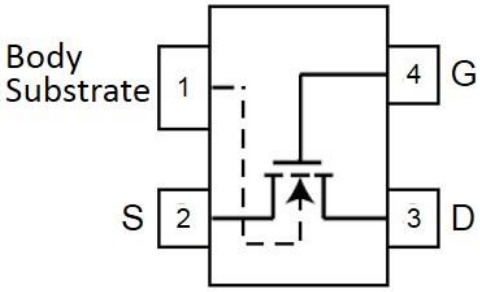
Top Views

SD210DE, SD214DE



TO-206AF
(TO-72)

SST210, SST214



TO-253
(SOT-143)

Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

Gate-Drain, Gate-Source Voltage . . . . . ± 40V
Gate-Substrate Voltage . . . . . ± 30V
Drain-Source Voltage (SD210DE/SST210) 30V
(SD214DE/SST214) 20V
Source-Drain Voltage (SD210DE/SST210) 10V
(SD214DE/SST214) 20V
Drain-Substrate Voltage (SD210DESST210) 30V
(SD214DE/SST214) 25V

Source-Substrate Voltage (SD210DE/SST210) 15V
(SD210DE/SST210) 25V
Drain Current 50mA
Lead Temperature (1/16" from ease for 10 seconds) . . . . . 300°C
Storage Temperature . . . . . -65 to 150°C
Operating Junction Temperature . . . . . -55 to 125°C
Power Dissipation* 300mW

Note:
* Derate 3mW/°C above 25°C

Specifications[a]

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	LIMITS 210 Series Min	LIMITS 210 Series Max	LIMITS 214 Series Min	LIMITS 214 Series Max	UNIT
Static									
Drain - Source Breakdown Voltage	$V_{(BR)DS}$	V_{GS} = V_{BS} = 0V, I_D = 10 µA		35	30				V
		V_{GS} = V_{BS} = -5V, I_D = 10 nA		30	10		20		
Source - Drain Breakdown Voltage	$V_{(BR)SD}$	V_{GD} = V_{BD} = -5V, I_S = 10 nA		22	10		20		
Drain - Substrate Breakdown Voltage	$V_{(BR)DBO}$	V_{GB} = 0V, I_D= 10 nA Source Open		35	15		25		
Source - Substrate Breakdown Voltage	$V_{(BR)SBO}$	V_{GB} = 0V, I_s = 10 µA Drain Open		35	15		25		
Drain – Source Leakage	$I_{DS(off)}$	V_{GS} = V_{BS} = -5V	V_{DS} = 10V	0.4		10			nA
			V_{DS} = 20V	0.9				10	
Source - Drain Leakage	$I_{SD(off)}$	V_{GD} = V_{BD} = -5V	V_{SD} = 10V	0.5		10			
			V_{SD} = 20V					10	
Gate Leakage	I_{GBS}	V_{DB} = V_{SB} = 0V, V_{GB} = ±40V		±0.001		±100		±100	pA
Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 1 µA , V_{SB} = 0V		0.8	0.5	1.5	0.1	1.5	V
Drain – Source On-Resistance	$r_{DS(on)}$	V_{SB} = 0V I_D = 1mA	V_{GS} = 5V (SD Series)	58		70		70	Ω
			V_{GS} = 5V (SST Series)	60		75		75	
			V_{GS} = 10V (SD Series)	38		45		45	
			V_{GS} = 10V (SST Series)	40		50		50	
			V_{GS} = 15V	30					
			V_{GS} = 20V	26					
			V_{GS} = 25V	24					

Specifications[a]

PARAMETER	SYMBOL[b]	TEST CONDITIONS[b]		TYP[c]	LIMITS 210 Series Min	LIMITS 210 Series Max	LIMITS 214 Series Min	LIMITS 214 Series Max	UNIT
Dynamic									
Forward Transconductance	g_{fs}	V_{DS} = 10V, V_{SB} = 0V, I_D = 20mA, f = 1kHz	SD Series	11	10		10		mS
			SST Series	10.5	9		9		
	g_{os}		All	0.9					
Gate Node Capacitance	$C_{(GS+GD+GB)}$	V_{DS} = 10V, f = 1MHz V_{GS} = V_{BS} = -15V	SD Series	2.5		3.5		3.5	pF
Drain Node Capacitance	$C_{(GD+DB)}$			1.1		1.5		1.5	
Source Node Capacitance	$C_{(GS+SB)}$			3.7		5.5		5.5	
Reverse Transfer Capacitance	C_{rss}		SST Series	4.2					
			SD Series	0.2		0.5		0.5	
Switching									
Turn-On Time	$t_{D(on)}$	SD Series Only V_{SB} = 0V, V_{IN} 0 to 5V, R_G = 25Ω V_{DD} = 5V, R_L = 680Ω		0.5		1		1	ns
	t_r			0.6		1		1	
Turn-Off Time	$t_{D(off)}$			2					
	t_f			6					

NOTES:

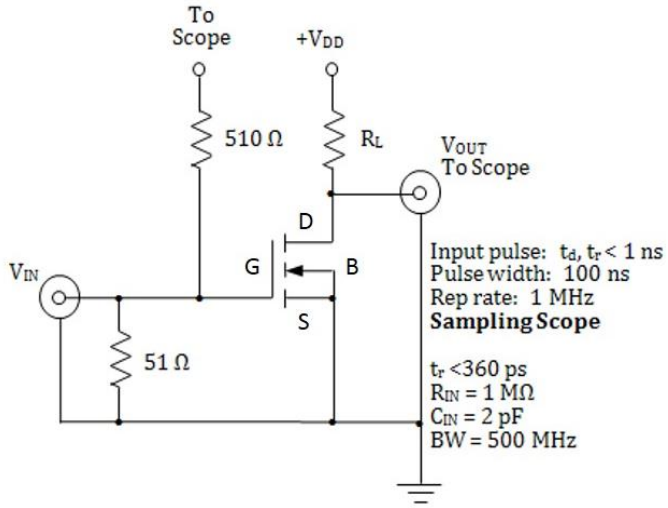
a. T_A = 25°C unless otherwise notes.

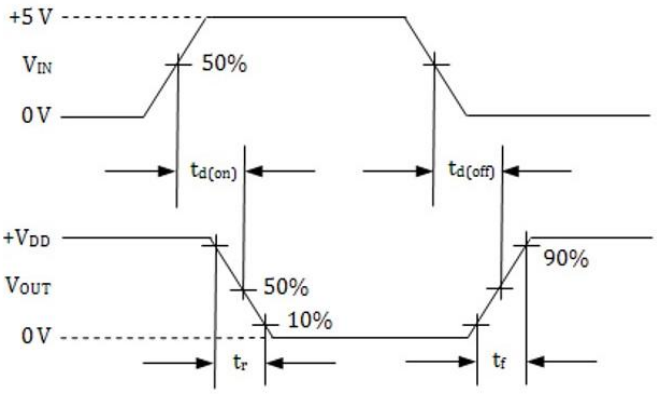
b. B is the body (substrate) and $V_{(BR)}$ is breakdown voltage.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

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Switching Time Test Circuit





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Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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Toplu alım ve teklif

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